

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)	Examiner: NYA	REC
MASAFUMI SANO ET AL.) :	Group Art Unit: 1741	JUL 5.
Application No.: 10/046,903)		TC 120
Filed: January 17, 2002)		. 70
For: METHOD OF PRODUCING ZINC OXIDE THIN FILM, METHOD OF PRODUCING PHOTOVOLTAIC DEVICE AND METHOD OF PRODUCING SEMICONDUCTOR) :) :		
DEVICE	:	June 20, 2002	

Office of Initial Patent Examination Customer Service Center Commissioner for Patents Washington, D.C. 20231

SECOND REQUEST FOR CORRECTED FILING RECEIPT

Sir:

Applicants' attorneys have received an official Corrected Filing Receipt in the above-identified application wherein an error has been noted. The Title remains incorrect and should read:

- -Method of producing zinc oxide thin film, method of producing photovoltaic device and method of producing semiconductor device- -.

A copy of the official Corrected Filing Receipt is attached with the proposed change marked in red. Issuance of a Corrected Filing Receipt with the correct data is accordingly respectfully requested.

Applicants' undersigned attorney may be reached in our New York office by telephone at (212) 218-2100. All correspondence should continue to be directed to our address given below.

Respectfully submitted,

Attorney for Applicants

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TOT CLAIMS IND CLAIMS DRAWINGS FIL FEE REC'D ATTY.DOCKET.NO **GRP ART UNIT** APPLICATION NUMBER FILING DATE 03560.002157 42 01/17/2002 1741 10/046,903

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5514 FITZPATRICK CELLA HARPER & SCINTO 30 ROCKEFELLER PLAZA NEW YORK, NY 10112



Receipt is acknowledged of this nonprovisional Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Filing Receipt Corrections, facsimile number 703-746-9195. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

Masafumi Sano, Kyoto-fu, JAPAN; Yuichi Sonoda, Nara-shi, JAPAN;

RECEIVED

JUL 5 - 2002

TC 1700

Domestic Priority data as claimed by applicant

THIS APPLICATION IS A DIV OF 09/074,699 05/08/1998 PAT 6.346.184 * (*)Data provided by applicant is not consistent with PTO records.

Foreign Applications

JAPAN 1997-121921 05/13/1997

If Required, Foreign Filing License Granted 02/19/2002

Projected Publication Date: 05/30/2002

Non-Publication Request: No

Early Publication Request: No

Title

Method of producing zinc oxide thin film method of producing photovoltaic device and method of producing semiconductor device insert 200 request

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